## NTC52300

## power cycling semiconductor life test system



|                              | AC Input Requirements:                      | Option 1. 208V 3 phase 5 wire, 208V Line to Line, 120V Line to Neutral (3 lines,neutral,gnd) |  |   |
|------------------------------|---|--|--|---|
| utilities                    |   | Option 2. 380V 3 phase 5 wire, 380V Line to Line, 220V Line to Neutral (3 lines,neutral,gnd) |  |   |
|                              |   | Option 3. 240V single phase 4 wire   | Line to Neutral (2 lines,neutral,gnd)                                      |   |
|                              |   | Option 4. 440V single phase 4 wire   | Line to Neutral (2 lines, neutral, gnd)                                    |   |
|                              | AC Breaker:<br>Service:<br>Maximum Current: | 120 A<br>50 A Each Line<br>220 VAC = 100A  |  |   |
| mechanical<br>specifications | Physical Dimensions:                        | Height:<br>Width:<br>Depth:<br>Weight:   | 75" (190.5 cm)<br>58" (147.3 cm)<br>45" (114.3 cm)<br>1500 lbs. (680.4 kg) |   |
|                              | Military Specifications:                    | ITC52300 Testers Conform to MIL-STD-750, Method 1026.5, 1027.3, 1036.3, 1037.3 and 1042.4    |  |   |
|                              | DUT Testing:                                | Device Boards:   | 16 Maximum   |   |
| electrical<br>specifications |   | VDD Supplies:  | 16   |   |
|                              |   | VDD Voltages:  | 24/48 Vdc Switchable   |   |
|                              |   | Max Current:   | 10 A per board   |   |
|                              |   | DUT Power:   | 480 watts at 48 volts p  | er board  |
| DUT board types              |   | Device Types   |  | Devices per DUT Board                               |
| Der Beard types              | ITC5230C DIGEN Type                         | Axial Lead Diodes and surface mounted Bridge Rectifiers                                      |  | 100 (25 per daughter board)                         |
|                              | ITC5230C DDGEN Type                         | Dual diode, common anode, or common cathode with the common lead in the center               |  | 16 (32 diodes total)                                |
|                              | ITC5230B Generic Type                       | N-Channel MOSFETs, P-Channel MOSFETs, or IGBTs   |  | 56 (4 per daughter board) 28 (2 per daughter board) |
|                              | ITC52300 GENC                               | N-Channel MOSFETs, P-Channel MOSFETs, or IGBTs   |  | 14 (1 per daughter board)<br>32                     |
|                              | ITC52300 BJTGEN                             | NPN AND PNP bipolar devices  |  | 32  |
|                              | ITC52300 GEN-VV                             | N-Channel MOSFETs, P-Channel MOSFETs, or IGBTs   |  | 28  |
|                              | ITC52300 GENBJT-VV                          | NPN AND PNP bipolar devices  |  | 28  |
|                              | ITC52300 GENSIC-VV                          | SiC MOSFETs, N-Channel and P-Channel   |  | 28  |
|                              | TC52300 GENJFET-VV                          | JFET devices,NPN and PNP   |  | 28  |
| computer                     | Controllers:                                | ITC52300 User Interface Windows Compatible Computer  |  |   |

Note: Specifications subject to change without notice.

## INTEGRATED TECHNOLOGY CORPORATION

1228 North Stadem Drive • Tempe, Arizona 85281 USA • Phone 480-968-3459 • Fax 480-968-3099 Sales@IntTechCorp.com